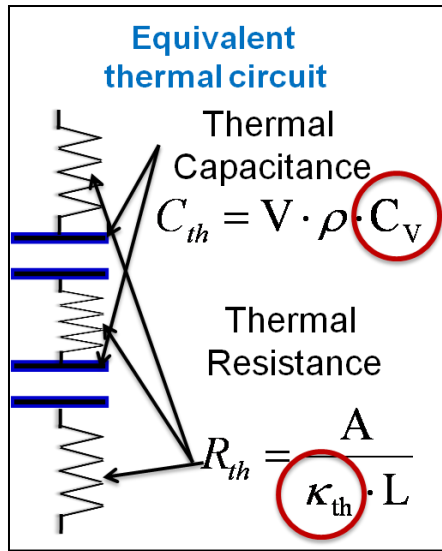
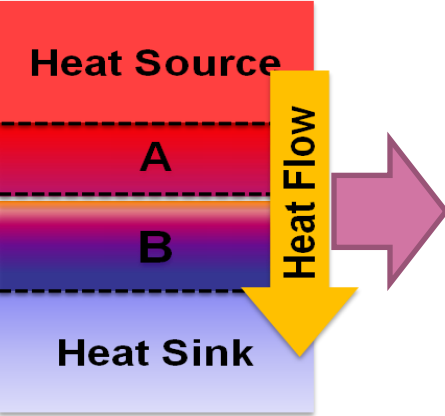


## Thermoelectric device



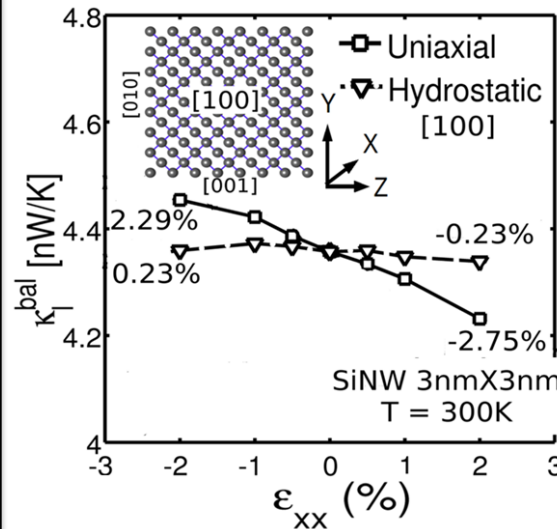
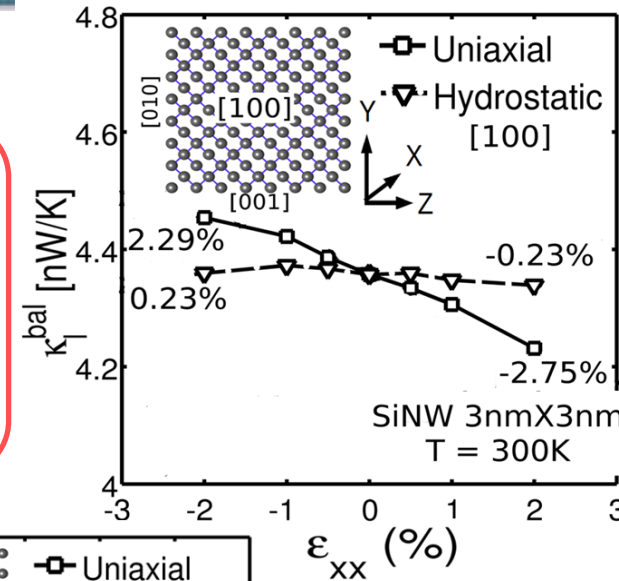
**Objective:** Engineering material **thermal properties** using strain to improve system level performance.

## Approach:

- [1] Modified Valence Force Field to model phonons in strained Si nanowires.
- [2] Study the effect of strain on specific heat ( $C_V$ ) and thermal conductance ( $k_l$ ).

## Results:

Uniaxial strain effectively tunes  $\kappa_l$ .



Hydrostatic strain tunes  $C_V$ .

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